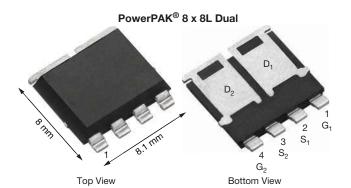
SQJQ906E

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Vishay Siliconix

Automotive Dual N-Channel 40 V (D-S) 175 °C MOSFET



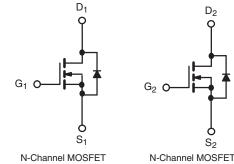
PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at V_{GS} = 10 V	0.0033				
I _D (A) per leg	95				
Configuration	Dual				
Package	PowerPAK 8 x 8L				

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Fully lead (Pb)-free device
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN



ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted) SYMBOL PARAMETER LIMIT UNIT Drain-source voltage 40 V_{DS} V Gate-source voltage V_{GS} ± 20 $T_C = 25 \circ C^a$ 95 Continuous drain current I_{D} T_C = 125 °C 55 Continuous source current (diode conduction) a ls 45 A Pulsed drain current b 300 I_{DM} Single pulse avalanche current 36 I_{AS} L = 0.1 mHSingle pulse avalanche energy E_{AS} 64 mJ $T_C = 25 \ ^{\circ}C$ 50 P_D Maximum power dissipation ^b W $T_{\rm C} = 125 \ ^{\circ}{\rm C}$ 17 -55 to +175 Operating junction and storage temperature range T_J, T_{stq} °C Soldering recommendations (peak temperature) d, e 260

THERMAL RESISTANCE RATINGS							
PARAMETER		SYMBOL	LIMIT	UNIT			
Junction-to-ambient	PCB mount ^c	R _{thJA}	100	°C/W			
Junction-to-case (drain)		R _{thJC}	3	0/10			

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 $\mu s,\,duty\,cycle \leq$ 2 $\,\%$
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK 8 x 8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$		1		1	1		1
PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		3	3.5	
Gate-source leakage	I _{GSS}	$V_{DS}=0~V,~V_{GS}=\pm~20~V$		-	-	± 100	nA
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 20 V	-	-	1	μA
	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = 40 V, T_{J} = 125 °C	-	-	50	
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	40	-	-	А
Drain-source on-state resistance ^a		$V_{GS} = 10 V$	I _D = 5 A	-	0.0027	0.0033	Ω
	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	$I_D = 5 \text{ A}, \text{T}_\text{J} = 125 \ ^\circ\text{C}$	-	-	0.0048	
		V _{GS} = 10 V	I _D = 5 A, T _J = 175 °C	-	-	0.0056	
Forward Transconductance ^b	g _{fs}	V _{DS} = 15 V, I _D = 15 A		-	75	-	S
Dynamic ^b							
Input capacitance	C _{iss}		V V _{DS} = 20 V, f = 1 MHz	-	2880	3600	pF
Output capacitance	C _{oss}	V _{GS} = 0 V		-	1635	2045	
Reverse transfer capacitance	C _{rss}			-	85	105	
Total gate charge ^c	Qg	V _{GS} = 10 V	V _{DS} = 20 V, I _D = 10 A	-	34	42	nC
Gate-source charge ^c	Q _{gs}			-	11	-	
Gate-drain charge ^c	Q _{gd}			-	4	-	
Gate resistance	Rg	f = 1 MHz		0.7	1.1	1.9	Ω
Turn-on delay time ^c	t _{d(on)}			-	14	19	
Rise time ^c	tr	$V_{DD} = 20 \text{ V}, \text{ R}_{L} = 2 \Omega$ $\text{I}_{D} \cong 10 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	4	6	ns
Turn-off delay time ^c	t _{d(off)}			-	26	35	
Fall time ^c	t _f			-	4	6	
Source-Drain Diode Ratings and Char	racteristics ^b						
Pulsed current ^a	I _{SM}			-	-	600	Α
Forward voltage	V _{SD}	$I_{\rm F} = 40$ A, $V_{\rm GS} = 0$		-	1	1.2	V

Notes

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

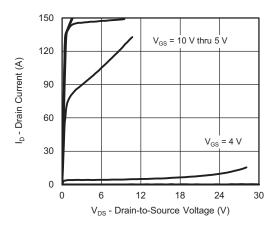
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

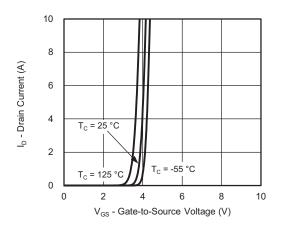
2



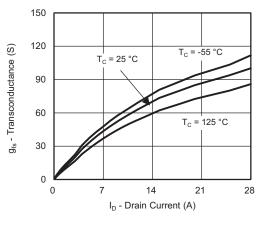
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



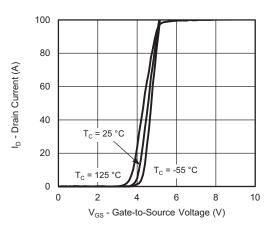
Output Characteristics



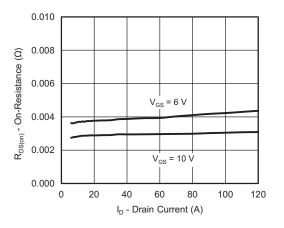
Transfer Characteristics



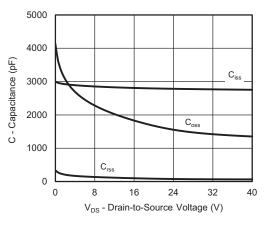
Transconductance



Transfer Characteristics



On-Resistance vs. Drain Current



Capacitance

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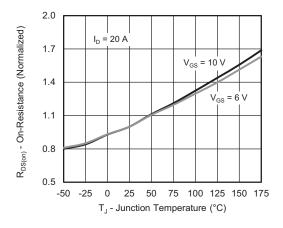
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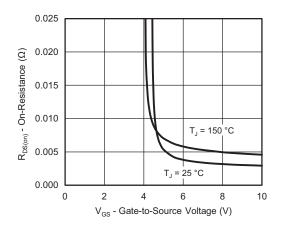
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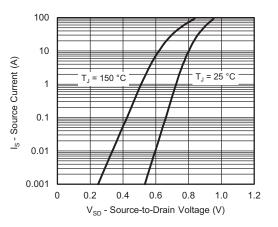
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



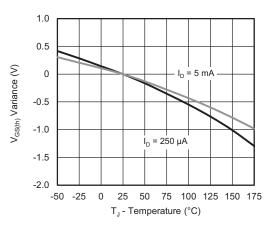
On-Resistance vs. Junction Temperature



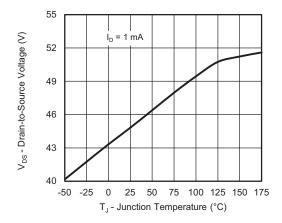
On-Resistance vs. Gate-to-Source Voltage

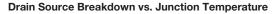


Source Drain Diode Forward Voltage



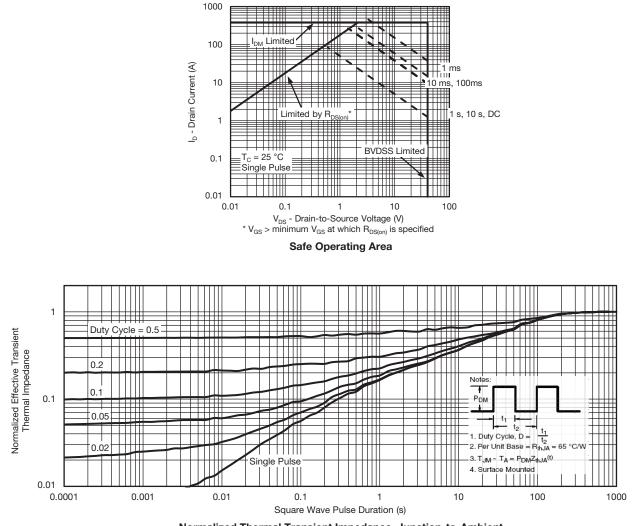
Threshold Voltage







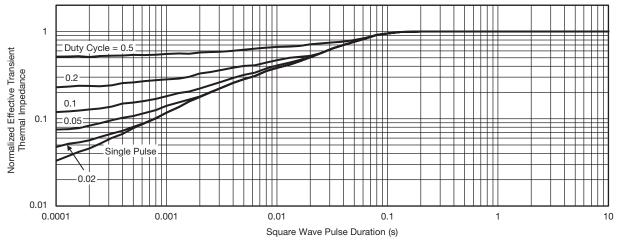
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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